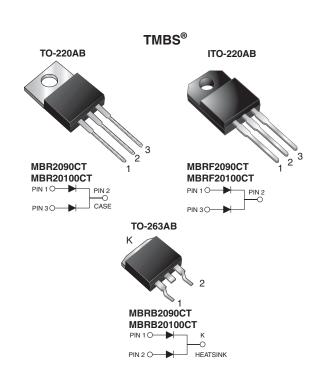
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RoHS

Dual Common-Cathode High Voltage Trench MOS Barrier Schottky Rectifier



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V_{RRM}	90 V to 100 V			
I _{FSM}	150 A			
V_{F}	0.65 V			
T_{J} max.	150 °C			
Package	TO-220AB, ITO-220AB, TO-263AB			
Diode variation	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Lower power losses, high efficiency
- · Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR2090CT	MBR20100CT	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V	
Working peak reverse voltage	V _{RWM}	90	100	V	
Maximum DC blocking voltage	V_{DC}	90	100	V	
Maximum average forward rectified current at T _C = 133 °C total device	1	20		Α	
per diode	I _{F(AV)}	10			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150		А	
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH per diode	E _{AS}	130		mJ	
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode	I _{RRM} 0.5		А		
Voltage rate of change (rated V _R)	dV/dt	10	000	V/µs	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	15	000	V	
Operating junction and storage temperature range	T _J , T _{STG}	-65 to	+150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	MAX.	UNIT
Maximum instantaneous forward voltage per diode	I _F = 10 A	T _C = 25 °C	V _F ⁽¹⁾	0.80	V
	I _F = 10 A	T _C = 125 °C		0.65	
	I _F = 20 A	T _C = 125 °C		0.75	
Maximum reverse current per diode at working peak reverse voltage		T _J = 25 °C	I _R ⁽²⁾	100	μΑ
		T _J = 125 °C		6.0	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ hetaJA}$	60	-	60	°C/W
	$R_{ heta JC}$	2.0	3.5	2.0	C/VV

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR20100CT-E3/4W	1.88	4W	50/tube	Tube		
ITO-220AB	MBRF20100CT-E3/4W	1.75	4W	50/tube	Tube		
TO-263AB	MBRB20100CT-E3/4W	1.38	4W	50/tube	Tube		
TO-263AB	MBRB20100CT-E3/8W	1.38	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

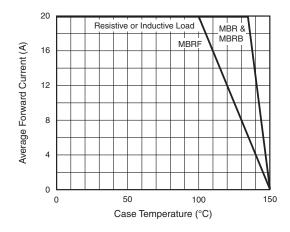


Fig. 1 - Forward Current Derating Curve

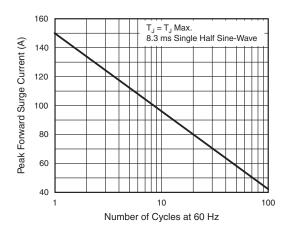


Fig. 2 - Maximum Non-Repetitive Peak Forward SurgeCurrent Per Diode



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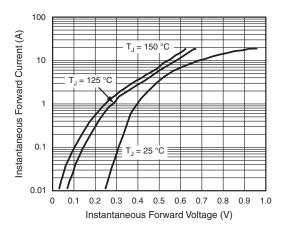


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

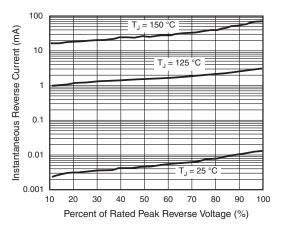


Fig. 4 - Typical Reverse Characteristics Per Diode

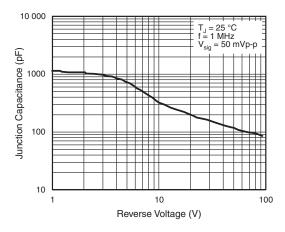


Fig. 5 - Typical Junction Capacitance Per Diode

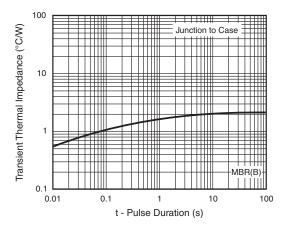


Fig. 6 - Typical Transient Thermal Impedance Per Diode

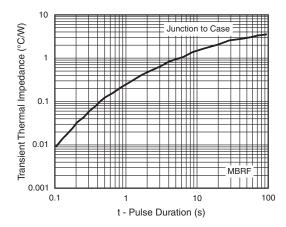


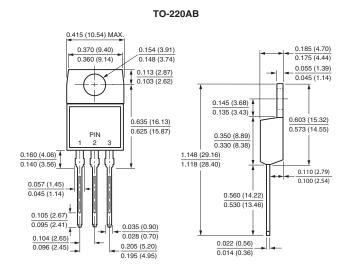
Fig. 7 - Typical Transient Thermal Impedance Per Diode

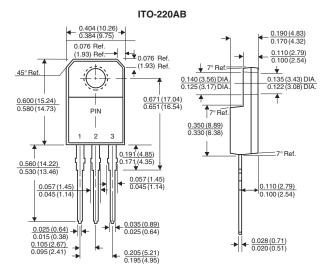


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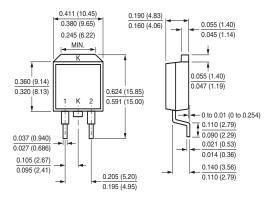
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

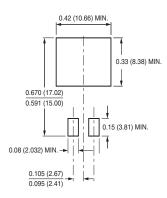




TO-263AB



Mounting Pad Layout





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